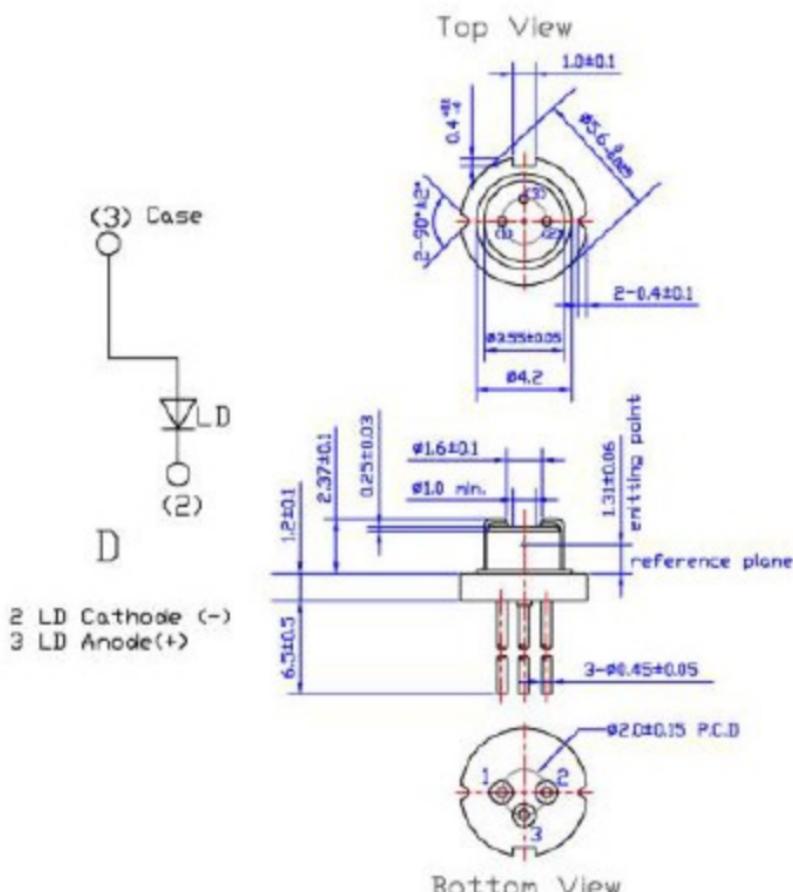


■ Specifications

- (1) Device: Laser Diode
(2) Structure: TO-18 ($\phi 5.6\text{mm}$), With Pb free glass cap, no PD
(3) Power Output: 500mW

■ External dimensions(Unit : mm)



■ Absolute Maximum Ratings($T_c=25^\circ\text{C}$)

Parameter	Symbols	Ratings	Units
Optical Output	P_o	500	mW
Reverse Voltage	V_r	2	V
Operating Temperature	T_{op}	-10~+40	°C
Storage Temperature	T_{stg}	-40~+85	°C

■ Electrical and Optical Characteristics($T_c=25^\circ\text{C}$)

Parameter	Symbols	Conditions	Min.	Typ.	Max.	Units
Threshold Current	I_{th}	$P_o=500\text{mW}$	-	70	100	mA
Operating Current	I_{op}	$P_o=500\text{mW}$	-	540	590	mA
Operating Voltage	V_{op}	$P_o=500\text{mW}$	-	1.9	1.95	Volts
Slope Efficiency	η	375mW-125mW	0.8	1.1	-	mW/mA
		$I_{375\text{mW}}-I_{125\text{mW}}$				
Beam Divergence (FWHM)	Parallel	$\theta_{//}$	$P_o=500\text{mW}$	-	10	- deg.
	Perpendicular	θ_{\perp}	$P_o=500\text{mW}$	-	31	- deg.
Lasing Wavelength*	λ	$P_o=500\text{mW}$	803	808	811	nm

◎ $\theta_{//}$ and θ_{\perp} are defined as the angle within which the intensity is 50% of the peak value.

■ Typical characteristic curves

Optical Output Power v.s. Forward Current

